

# C230, C231, C230()3, C231()3, C232, C233 SERIES

High-reliability discrete products and engineering services since 1977

## SILICON CONTROLLED RECTIFIERS

#### FEATURES

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak repetitive off state voltage <sup>(1)</sup>			
(T <sub>J</sub> = -40 to +100°C)			
C230F, C231F, C230F3, C231F3, C232F, C233F		50	
C230A, C231A, C230A3, C231A3, C232A, C233A		100	
C230B, C231B, C230B3, C231B3, C232B, C233B	Vrrm, Vdrm	200	Volts
C230C, C231C, C230C3, C231C3, C232C, C233C		300	
C230D, C231D, C230D3, C231D3, C232D, C233D		400	
C230E, C231E, C230E3, C231E3, C232E, C233E		500	
C230M, C231M, C230M3, C231M3, C232M, C233M		600	
Peak non-repetitive reverse voltage			
(T <sub>J</sub> = -40 to +100°C)			
C230F, C231F, C230F3, C231F3, C232F, C233F		75	
C230A, C231A, C230A3, C231A3, C232A, C233A		150	
C230B, C231B, C230B3, C231B3, C232B, C233B	V <sub>RSM</sub>	300	Volts
C230C, C231C, C230C3, C231C3, C232C, C233C		400	
C230D, C231D, C230D3, C231D3, C232D, C233D		500	
C230E, C231E, C230E3, C231E3, C232E, C233E		600	
C230M, C231M, C230M3, C231M3, C232M, C233M		720	
Forward current RMS	I <sub>T(RMS)</sub>	25	Amps
Peak surge current			4
(one cycle, 60Hz, T <sub>c</sub> = -40 to +100°C)	ITSM	250	Amps
Circuit fusing considerations	124		A2-
(T <sub>c</sub> = -40 to +100°C, t = 8.3ms)	1-1	260	A-S
Peak gate power	Р <sub>GM</sub>	5	Watts
Average gate power	P <sub>G(AV)</sub>	0.5	Watts
Peak forward gate current	Igm	2	Amps
Operating junction temperature range	T,	-40 to +100	°C
Storage temperature range	$T_{stg}$	-40 to +125	°C
Mounting torque		30	In. lb.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Maximum	Unit
Thermal resistance, junction to case			
Pressfit	R <sub>eJC</sub>	1	°C/W
Isolated stud		1.15	



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Characteristic	Symbol	Min.	Тур.	Max.	Unit
Peak forward or reverse blocking current					
(Rated V <sub>DRM</sub> or V <sub>RRM</sub> , gate open)					
T <sub>c</sub> = 25°C	IDRM, IRRM	-	-	10	μΑ
T <sub>c</sub> = 100°C		-	-	1	mA
Forward "on" voltage					Valta
(I <sub>TM</sub> = 100A peak, pulse width $\leq$ 1ms, duty cycle $\leq$ 2%)	VTM	-	-	1.9	Volts
Gate trigger current (C230, C230()3, C232 series)	IGT				mA
$(V_D = 12V, R_L = 120\Omega)$		-	-	25	
$(V_D = 12V, R_L = 60\Omega, T_C = -40^{\circ}C)$		-	-	40	
Gate trigger current (C231, C231()3, C233 series)	I <sub>GT</sub>				mA
$(V_D = 12V, R_L = 120\Omega)$		-	-	9	
$(V_D = 12V, R_L = 60\Omega, T_C = -40^{\circ}C)$		-	-	20	
Gate trigger voltage (continuous dc)					Volts
$(V_D = 12V, R_L = 120\Omega)$	V <sub>GT</sub>	-	-	1.5	
$(V_D = 12V, R_L = 60\Omega, T_C = -40^{\circ}C)$		-	-	2	
$(V_D = Rated V_{DRM}, R_L = 1000\Omega, T_C = 100^{\circ}C)$		0.2	-	-	
Holding current	Iн				mA
$(V_D = 24V, \text{ gate open}, I_T = 0.5A)$					
T <sub>c</sub> = 25°C		-	-	50	
T <sub>c</sub> = -40°C		-	-	100	
Turn-on time (t <sub>d</sub> +t <sub>r</sub> )	t <sub>gt</sub>				μs
$(I_{TM} = 25A, I_{GT} = 40mA, V_D = Rated V_{DRM})$		-	1	-	
Turn-off time	tq				μs
$(I_{TM} = 10A, I_R = 10A, pulse width = 50\mu s, dv/dt = 20V/\mu s,$					
V <sub>D</sub> = Rated V <sub>DRM</sub> )		-	25	-	
(T <sub>c</sub> = 100°C)		-	35	-	
Forward voltage application rate	dv/dt				V/µs
$(V_D = rated V_{DRM}, T_C = 100^{\circ}C)$		-	100	-	

**ELECTRICAL CHARACTERISTICS** ( $T_c = 25^{\circ}C$  unless otherwise specified)



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## MECHANICAL CHARACTERISTICS

Case	Digi PF2 (C232 and C233 SERIES)
Marking	Alpha-Numeric



	DIGI PF2			
	Inc	hes	Millim	neters
	Min	Max	Min	Max
Α	0.501	0.505	12.730	12.830
В	0.465	0.475	11.810	12.060
С	0.330	0.380	8.390	9.650
Е	0.100	-	2.540	-
F	0.035	0.085	0.890	2.160
J	0.080	0.097	2.040	2.460
K	-	0.800	-	20.320
Ν	-	0.510	-	12.950
Q	0.065	0.160	1.650	4.060

### MECHANICAL CHARACTERISTICS

Case TO-48 (C230,C231)		
Marking	Alpha-Numeric	
Polarity	As Marked	



	TO-48			
	Inches Millimeters			
	Min	Max	Min Max	
CD	-	0.543	-	13.793
СН	-	0.550	-	13.970
HF	0.544	0.563	13.817	14.301
OAH	-	1.193	-	30.303
SL	0.422	0.453	10.718	11.507
ФТ	0.125	0.165	3.175	4.191
<b>ΦT</b> <sub>1</sub>	0.060	0.075	1.524	1.905



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#### MECHANICAL CHARACTERISTICS

Case	TO-48 ISO (C230()3, C231()3 SERIES)	
Marking	Alpha-Numeric	
Polarity	As Marked	





	TO-48 ISO			
	Inches Millimeters			
	Min	Max	Min	Max
Α	0.551	0.559	14.000	14.200
В	0.501	0.505	12.730	12.830
С	-	1.280	-	32.510
F	-	0.160	-	4.060
Н	-	0.265	-	6.730
J	0.420	0.455	10.670	11.560
Κ	0.300	0.350	7.620	8.890
L	0.255	0.275	6.480	6.990
Q	0.055	0.085	1.400	2.160
Т	0.135	0.150	3.430	3.810





